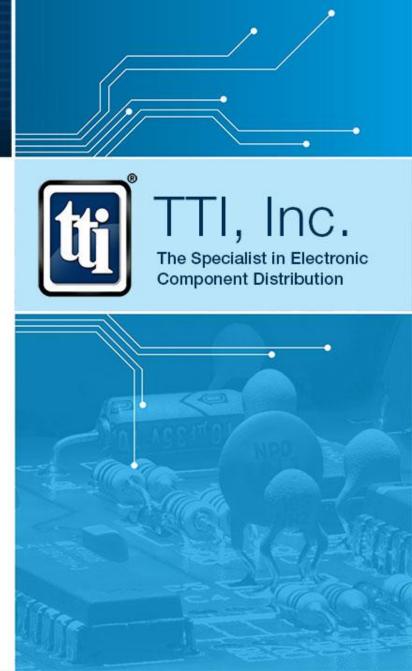




Discrete Semiconductors in a Nutshell



Content 1/2



Optical Solutions

PROXIMITY SENSORS - LIGHT TO DIGITAL - VCNL4X-SERIES

VCNL4035X01 - FULLY INTEGRATED PROXIMITY AND AMBIENT LIGHT SENSOR

TSOPx9xxxTR1 - LOWEST SIDE-VIEW IR-RECEIVER PROFILE

TSOP33x, TSOP53x SERIES - OUT PERFORMANCE FULL LENSE PACKAGES

TRANSMISSIVE SENSORS

SOLID-STATE RELAYS VOR SERIES

LARGE PIN PHOTO DIODES

Diode Solutions

FRED Pt - HIGH POWER DENSITY RECTIFIERS IN SMPD PACKAGE (TO-263AC)

<u> VTVSxxGMF SERIES - 400 WATT TVS DIODES IN SMF PACKAGE (DO-219AB)</u>

<u>eSMP® SERIES - SMALL AND LOW PROFILE PACKAGE SOLUTIONS FOR SELECT DIODES AND RECTIFIERS</u>

STANDARD RECOVERY RECTIFIERS - ESD CAPABILITY

TRENCH MOS BARRIER SCHOTTKY TECHNOLOGY IN SPACE-SAVING FOOTPRINTS AND LOW PROFILE PACKAGE SOLUTIONS

FRED Pt® RECTIFIERS IN eSMP® SERIES - SPACE-SAVING FOOTPRINTS AND LOW PROFILE PACKAGE SOLUTIONS

PLZ-SERIES – ZENER DIODES IN MicroSMF (DO219AC-PACKAGE9

ESD PROTECTION DIODES IN ULTRA COMPACT CHIP LEVEL PACKAGE (CLP)

TRANSZORB TVS IN SMB(DO-214AA) - OFFER TIGHTER ± 3.5 % BREAKDOWN VOLTAGE TOLERANCE

TRANSIENT VOLTAGE SUPPRESSORS eSMP-SERIES PACKAGES



IC Solutions

SIC46x microBUCK SERIES - 4.5V TO 60V BUCK REGULATORS

MOSFET Solutions

LOW VOLTAGE TRENCH MOSFETS

MEDIUM VOLTAGE TRENCH MOSFETS

TRENCHFET AND HIGH VOLTAGE E-SERIES MOSFETS

AUTOMOTIVE TrenchFET - SQ-Series POWER MOSFETS

POWERPAIR MOSFETS - INTEGRATED DUAL-MOSFET POWER STAGE

P-CHANNEL MOSFETS -12V TO -40V TrenchFET GEN III and IV



PROXIMITY SENSORS

LIGHT TO DIGITAL – VCNL4X SERIES

IN A NUTSHELL



Presence and proximity sensing up to 1.5 meters

Programmable emitter current

Upper and lower thresholds, and interrupt functions

16-bit resolution



Low profile of 0.85 mm

Connects directly to a microcontroller via I²C



Fully integrated solutions with infrared emitter, proximity photodiode, and signal conditioning IC

Automotive-qualified options (-X01)





APPLICATIONS

- Mobile devices (e.g. smart phones, touch phones, PDAs, GPS) for touch screen locking, power saving
- · Automotive for presence detection
- · Attract mode engagement
- · Automatic doors, faucets, and toilets
- · Robots for cliff detection and docking
- Toys for edge of table detection and collision avoidance











CC	M	PE	TIT	IVE	
Α[)V/	4N	TA(ŝΕ	

 Sensors include 16-bit ambient light sensor at no extra cost

 Optical noise suppression



Part Number	L	W	Н	IR LED	Prox	ALS	Interrupt	Package	AEC-Q101	Range	Remark
VCNL4010	3.9	3.9	0.7	•	•	• • •		FAM		0.2 m	Lowest height
VCNL4020X01	4.9	2.4	0.8	•	•	•	•	FAM	•	0.2 m	Highest operating temperature in market
VCNL3020	4.9	2.4	0.8	•	•		•	FAM		0.2 m	Low height, proximity only
VCNL4040	4	2	1.1	•	•	•	•	PCB		0.2 m	Smallest package in the market. Improved ALS with Filtron™
VCNL4200	8	3	1.8	•	•	•	•	PCB		1.5 m	1.5 meter proximity



VCNL4035X01 OPTICAL SENSOR FULLY INTEGRATED PROXIMITY AND AMBIENT LIGHT SENSOR

High resolution proximity and ambient light sensor at 16 bit





Low profile (0.75 mm)package

HALOGEN FREE

RoHS AEC-0101 Qualified COMPLIANT

COMPETITIVE ADVANTAGE

- 16-bit resolution for not only ALS but also for proximity
- External emitters for gesture recognition for design flexibility
- Excellent sunlight cancellation capability

Sunlight Cancellation





Outstanding sensitivity allowing high object detection distance



Excellent background light cancellation



16-bit resolution for ambient light and proximity sensing

2D and **3D** gesture function supported

APPLICATIONS

Ideal for gesture recognition in automotive, consumer, and industrial applications









PRIMARY CHARACTERISTICS	
Operating Range (V)	2.5 to 3.6
I ² C BUS Voltage Range (V)	1.8 to 5
IRED Pulse Current (mA)	200
Ambient Light Range (lx)	0.004 to 4192
Ambient Light Resolution (Ix)	0.004
Output Code 16 bit	I ² C





VCNL4035X01 Optical Sensor

Fully integrated Automotive Grade proximity and ambient light sensor for gesture recognition. Featuring Filtron™ technology, the Vishay Semiconductors VCNL4035X01 combines photo detectors for proximity and ambient light, a signal conditioning IC, a 16-bit ADC, and a driver for up to three external IREDs in one compact 4 mm by 2.36 mm by 0.75 mm surface-mount package.

Advantages	Benefits		
16-bit high resolution	Superior sensing capabilities for both proximity and ambient light		
IDRIVER FOR LID TO THEE EXTERNAL IR FLUS	Enables more intricate gestures and better resolution for swiping gestures		
Programmable interrupt function	Allows both high and low thresholds to be set to reduce the overall power consumption		

VCNL4035X01 datasheet
Optical Sensors Portfolio
AppNote - Designing the VCNL4035X01 Into an Application
Demo board and software
<u>Video - VCNL4035X01</u>





TSOPx9xxxTR1 SERIES

LOWEST SIDE-VIEW IR RECEIVER PROFILE

2 V supply voltage available





Low profile (2.6 mm) side-view package

HALOGEN FREE ROHS COMPLIANT

COMPETITIVE ADVANTAGE

- Winged package for "in the board" mounting
- High sensitivity and long range
- · Reflow solderable







Excellent noise suppression



Very fast response time

Tape and reel packaging



IN A NUTSHELL

All AGC variants are available (36 kHz to 56 kHz)

APPLICATIONS

Ideal for space-constrained electronics







STREAMING MEDIA PLAYERS

PRIMARY CHARACTERISTICS				
Dimensions Width, Height, Depth (mm) 6.8 x 2.6 x 5.3				
Supply Current (typ) 0.35 mA				
Minimum Irradiance (tvp) 0.08 mW/m ²				





TV-Cast SMD IR Receivers

New series of miniature infrared (IR) receiver modules for IR remote control applications in flatpanel TVs and monitors for superior remote control performance. For front mounting in 3 mm frames the TSOP39xxxTR1 and TSOP59xxxTR1 series devices are industry first; offered in the TVCastSMD side-view, winged, surface-mount package with an ultra low height of 2.6 mm.

Advantages	Benefits	
Side-view, winged package with ultra low 2.6 mm height	Front mounting in tight 3 mm frames for superior remote control performance	
Photodetector, preamplifier circuit, and IR filter in a single 4-pin epoxy package featuring a two-lens design	High sensitivity with transmission range up to 45 meter, improved immunity against ambient light, and insensitive to supply voltae variations and ripple noise	

TVCastSMD Portfolio					
AppNote - Using Vishay Infrared Receivers in a Wi-Fi Environment					
AppNote - Data Formats for IR Remote Control					
Video - TVCast / TVCastSMD save space in consumer products					
Video - Minimold IR Receivers withstand infrared reflow soldering					
3D Models (zip)					





TSOP33x, TSOP53x SERIES

OUT-PERFORMS FULL LENS PACKAGES

Supports IR reflow soldering





Available in two holder and three bend options, including a top-view surface-mount version

HALOGEN FREE ROHS

COMPETITIVE ADVANTAGE

- Smaller outline and lower cost than full lens packages
- Robust RF with enhanced optical filter against out of band optical noise
- Pin in paste capable
 TS0P53xxxP10P or P16P side-view
 holder for 1.0 mm to 1.6 mm PCB
 thickness







Superior angular performance with off-angles up to 45°

Low current consumption





Narrow optical filter option available

Pin to pin compatible with market standard



IN A NUTSHELL

- All AGC variants are available (36 kHz to 56 kHz)
- TSSP530xx series for mid range sensor applications available
- Several mechanical variants available (holder, bends, and cuts)

APPLICATIONS

FLAT SCREEN TV









Key Specifications	TSOP33xxx	TSOP53xxx	
Typical irradiance at 0° (mW/m2)	0.08 0.12		
Supply voltage (V)	2.5 to 5.5		
Typical supply current (mA)	0.35 0.7		
Transmission range (m)	45		
Carrier frequencies (kHz)	30 to 56		





TSOP33x, TSOP53x Minimold Series

Minimold package delivers the same RF noise rejection as Minicast while surpassing the high optical performance of Mold package devices. For products such as televisions, set-top boxes, air conditioners, and hi-fi audio systems, the devices provide high sensitivity with typical irradiance down to 0.08 mW/m2 at 0° for the TSOP33xxx series and 0.12 mW/m2 for the TSOP53xxx series

Advantages	Benefits
Smaller package with bigger lense	Better price performance ratio
Improved RF robustness	Absolute design freedom for STB designers
Qualified for Reflow soldering	DF1P SMD version for pick and place, or P10P/P16P version for Pin in paste process

Product Portfolio
Product Brochure
Application Note: Using Vishay Infrared Receivers in a Wi-Fi Environment
<u>Video- Minimold IR Receivers</u>
<u>3D - Models</u>





TRANSMISSIVE SENSORS

IN A NUTSHELL



SURFACE-MOUNT



Wide gap of 3 mm

Moisture sensitivity level (MSL) of 1 Surface-mount package Rugged, single piece construction

Output current of 1.6 mA



Compact size, 5.5 mm x 4.0 mm x 4.0 mm Automotive qualified, AEC-Q101

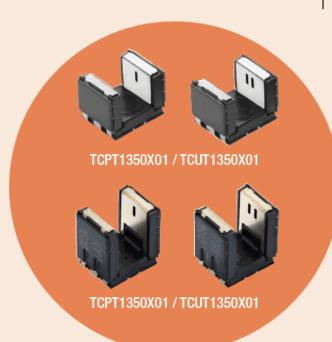


Rise time of 9 μs, typical

Deep slot for **turn and push** function

Operating temperature up to +125°C

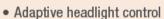




Part Number	TCPT1350X01	TCUT1350X01	TCPT1600X01	TCUT1600X01				
Single Channel	•		•					
Dual Channel		•		•				
Slot Depth	2.8	2.8	4.5	4.5				
LxWxH	5.5 mm x 4 r	nm x 4 mm	5.5 mm x 4 mm x 5.7 mm					
Function	Presence of object determines speed of turn	Determines speed and direction of turn	Turn and push function presence of object determines speed of turn	Turn and push function determines speed and direction of turn				
Gap	3 mm							
Operating Temperature	-40 °C to	+125 °C	-40 °C to +105 °C					
Output Current	1.6 m A at I _F = 15 mA							
On / Off Time	9 µs, 16 µs							

APPLICATIONS

- · Gear shift
- Ignition lock



- · Climate control knobs
- Latches
- Simple encoders
- Switches
- · Motor speed and travel distance

COMPETITIVE ADVANTAGE

- Extremely high operating temperature

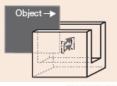
AUTOMOTIVE

- Package design ensures alignment of emitter and detector
- High photo current output allows lower forward current of emitter





How it works: simple encoder drawings









SOLID-STATE RELAYS

NUTSHELL

VOR SERIES

High reliability and noiseless switching (no click)



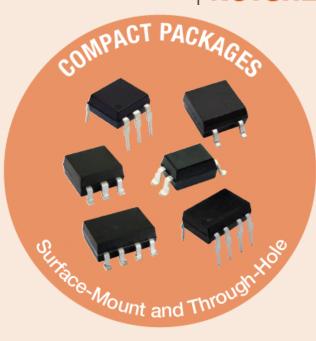


Tiny footprint relative to electromechanical relays

Fast switching times







APPLICATIONS









MANAGEMENT MEASUREMENT EQUIPMENT

INDUSTRIAL







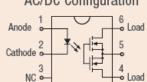
METERING

TELECOMMUNICATION

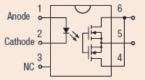
INSTRUMENTATION

AC AND DC CONFIGURATION WITH SSRs

AC/DC Configuration







	VOR1121A6	VOR1121B6	VOR2121A8	VOR2121B8	VOR1142M4	V0R1142B4	VOR1142A6	V0R1142B6	V0R2142A8	VOR2142B8
Single / Dual Channel	Single	Single	Dual	Dual	Single	Single	Single	Single	Dual	Dual
Package	DIP-6	SMD-6	DIP-8	SMD-8	SOP-4	SMD-4	DIP-6	SMD-6	DIP-8	SMD-8
Isolation Test Voltage (V _{RMS} / 1 min)	5300	5300	5300	5300	3750	5300	5300	5300	5300	5300
Typical On-Resistance (Ω)	12	12	12	12	22	22	22	22	22	22
Load Voltage (V)	250	250	250	250	400	400	400	400	400	400
Typical Turn-On Time (ms)	0.2	0.2	0.2	0.2	0.2	0.13	0.13	0.13	0.13	0.13
Typical Turn-Off Time (ms)	0.03	0.03	0.03	0.03	0.05	0.05	0.05	0.05	0.05	0.05



VORx Solid-State Relay Series

Vishay's solid-state relays (SSRs) designed to deliver superior electrical characteristics for telecommunications, industrial, security system, and metering applications. Vishay's VORx Series provide provide faster, bounce-free switching and a wider operating temperature range, and are more cost-effective than electro-mechanical relays.

Advantages	Benefits
Tiny package foot print options	Saves board space compared to bulky electro- mechnical relays
High Reliability	Superior performance
Fast Switching and low on-resistance	Faster applications and less power consumption

VORx Solid-State Relay Products					
<u>3D Models</u>					
FAQ: Solid-State Relays					
Video: Benefits of SSRs over Mechnical Relays					





LARGE PIN PHOTO DIODES A

7.5 mm² ACTIVE AREA

Radiant sensitive area of **7.5 mm²**





High photo sensitivity

Low profile of 0.9 mm





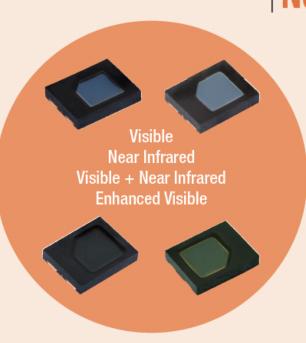
Rise and fall time down to 5 ns

Excellent photocurrent linearity

Narrow variance of output current

from part to part





APPLICATIONS

Wearables

- Fitness bands
- Smart Watches





Medical

- Pulse Oximetry
- Blood Analysis

Automotive



- Rain-Light-Tunnel Sensor
- Solar sensor

Part Number	Spectral Bandwidth (nm)	Peak Wavelength λp (nm)	OutputCurrent (µA)	Angle of Half Sensitivity, φ (±deg)	Photo Sensitive Area (mm²)	Package Dimensions L x W x H (mm)	Competitive Advantages								
<u>VEMD5010X01</u>	430 to 1100	940	48				AEC-Q101 qualified								
<u>VEMD5060X01</u>	350 to 1070	820	26				Fastest rise and fall times. AEC-Q101 qualified								
<u>VEMD5080X01</u>	350 to 1100	950	45				Enhanced sensitivity to visible light. AEC-Q101 qualified	Unique FAM							
<u>VEMD5110X01</u>	790 to 1050	940	48	65	7.5	5 x 4 x 0.9	Daylight blocking filter. AEC-Q101 qualified	packaging allows for high operating							
<u>VEMD5160X01</u>	700 to 1070	840	26											Daylight blocking filter with fastest rise and fall times. AEC-Q101 qualified	temperature up to +110 °C
<u>VEMD5510C</u>	440 to 700	550	0.6										Not sensitive to infrared radiation		
VEMD5510CF	440 to 620	540	0.25				Not sensitive to infrared radiation and matches human eye sensitivity								





FRED Pt® RECTIFIERS IN SlimDPAK PACKAGE IN A

INCREASE POWER DENSITY AND IMPROVE THERMAL PERFORMANCE

NUTSHELL

Reverse voltages: 200 V and 600 V





Ultrafast recovery times down to 14 ns

Low forward drop reduces power losses and improves efficiency





Footprint compatible with DPAK with 43 % lower profile for slimmer end products while heatsink area is 14 % larger for lower thermal resistance



AUTOMOTIVE and Commercial / Industrial GRADE Versions Available



FRED Pt® (Fast Recovery Epitaxial Diodes) products are based on a Pt doping technology that allows maximum operating junction temperature

Up to 175 °C





AUTOMOTIVE ECU, ABS, and HID / LED lighting



Telecom power supplies



DC/DC CONVERTERS

Vishay P/N	I _{F(KI)} (A)	V _{BR} (V)	V, (V)	atl _F (A)	t,, (ns)	I _{FSM} (A)	Tյmax. (°C)	AEC-Q101 Available
VS-4EVH02HM3	4	200	0.71	4	16	100	175	Yes
<u>VS-4EVH02-M3</u>	4	200	0.71	4	16	100	175	No
VS-6CVH02HM3	2 x 3	200	0.75	3	20	140	175	Yes
<u>VS-6CVH02-M3</u>	2 x 3	200	0.75	3	16	100	175	No
VS-8CVH02HM3	2 x 4	200	0.71	4	16	200	175	Yes
<u>VS-8CVH02-M3</u>	2 x 4	200	0.71	4	16	200	175	No
<u>VS-10CVH02HM3</u>	2 x 5	200	0.74	5	16	200	175	Yes
<u>VS-10CVH02-M3</u>	2 x 5	200	0.74	5	16	200	175	No
VS-6EVL06HM3	6	600	0.98	6	34	80	175	Yes
VS-6EVL06-M3	6	600	0.98	6	34	80	175	No
VS-6EVH06HM3	6	600	1.26	6	16	70	175	Yes
<u>VS-6EVH06-M3</u>	6	600	1.26	6	16	70	175	No
VS-6EVX06HM3	6	600	1.65	6	14	50	175	Yes

Vishay P/N	I _{Foto)} (A)	V _{er} (V)	V <u>.</u> (V)	at I _F (A)	t,, (ns)	I _{FSM} (A)	T _J max. (°C)	AEC-Q101 Available
VS-6EVX06-M3	6	600	1.65	6	14	50	175	No
VS-8EVL06HM3	8	600	0.98	8	34	130	175	Yes
VS-8EVL06-M3	8	600	0.98	8	34	130	175	No
VS-8EVH06HM3	8	600	1.30	8	16	90	175	Yes
<u>VS-8EVH06-M3</u>	8	600	1.30	8	16	90	175	No
VS-8EVX06HM3	8	600	1.40	8	14	80	175	Yes
VS-8EVX06-M3	8	600	1.40	8	14	80	175	No
VS-15EVL06HM3	15	600	0.98	15	38	180	175	Yes
VS-15EVL06-M3	15	600	0.98	15	38	180	175	No
<u>VS-15EVU06HM3</u>	15	600	1.10	15	26	160	175	Yes
<u>VS-15EVU06-M3</u>	15	600	1.10	15	26	160	175	No
VS-15EVH06HM3	15	600	1.20	15	20	120	175	Yes
VS-15EVH06-M3	15	600	1.20	15	20	120	175	No



FRED Pt® RECTIFIERS IN SMPD (TO-263AC) IN A

OFFER HIGHER POWER DENSITY

IN A NUTSHELL

FEATURES

- Hyperfast and ultrafast recovery
- Fast and soft recovery (down to 25 ns)
- Low forward voltage drop (down to 0.75 V typ.)
- · AEC-Q101 qualified

REDUCED POWER LOSSES



Reduced noise



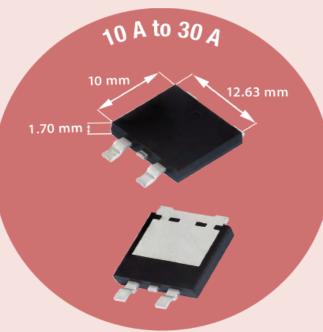
Reduced EMI

MORE EFFICIENT DESIGNS

FRED Pt[®] technology allows high operating temperatures to +175 °C

+175 °C

operating temperature



APPLICATIONS

AUTOMOTIVE and INDUSTRIAL



EV / HEV battery charging systems

SMPD package is **compatible** with **D**²**PAK footprint** but with **lower profile**

14.45 mm

Vishay P/N	Туре	Diode Variation	I _{F(AV)} (A)	V _R (V)	V _F Typ at Rated I (V)	T _{rr} Typ (ns)	AEC-Q101
<u>VS-10CDH06-M3</u>	Hyperfast	Dual	2 x 5	600	1	35	No
<u>VS-10CDH06HM3</u>	Hyperfast	Dual	2 x 5	600	1	35	Yes
VS-12CDU06-M3	Ultrafast	Dual	2 x 6	600	0.89	45	No
<u>VS-12CDU06HM3</u>	Ultrafast	Dual	2 x 6	600	0.89	45	Yes
VS-16CDH02-M3	Hyperfast	Dual	2 x 8	200	0.77	27	No
<u>VS-16CDH02HM3</u>	Hyperfast	Dual	2 x 8	200	0.77	27	Yes
<u>VS-16CDU06-M3</u>	Ultrafast	Dual	2 x 8	600	0.94	45	No
VS-16CDU06HM3	Ultrafast	Dual	2 x 8	600	0.94	45	Yes

Vishay P/N	Туре	Diode Variation	I _{F(AV)} (A)	V _R (V)	V _F Typ at Rated I (V)	T _{rr} Typ (ns)	AEC-Q101
VS-16EDH02-M3	Hyperfast	Single	16	200	0.75	32	No
<u>VS-16EDH02HM3</u>	Hyperfast	Single	16	200	0.75	32	Yes
VS-16EDU06-M3	Ultrafast	Single	16	600	0.91	55	No
VS-16EDU06HM3	Ultrafast	Single	16	600	0.91	55	Yes
VS-20CDH02-M3	Hyperfast	Dual	2 x 10	200	0.77	25	No
<u>VS-20CDH02HM3</u>	Hyperfast	Dual	2 x 10	200	0.77	25	Yes
VS-30CDU06-M3	Ultrafast	Dual	2 x 15	600	0.9	55	No
VS-30CDU06HM3	Ultrafast	Dual	2 x 15	600	0.9	55	Yes





FRED Pt® Rectifiers in the SMPD (TO-263AC) Package

10 A to 30 A FRED Pt® hyperfast and ultrafast recovery rectifiers in the SMPD (TO-263AC) package combine extremely fast and soft recovery characteristics with low leakage current and low forward voltage drop, to reduce switching losses and over-dissipation in automotive and telecom applications.

Advantages	Benefits
Increased power density	More efficient and slimmer end products
Operating junction temperature range from -55 °C to +175 °C	More robust designs
Low profile (< 1.7 mm) SMPD (TO-263AC) package	High density alternative to TO-263 (D2PAK) package

Product sheet
Press release





VTVSxxGSMF SERIES

400 W TVS IN SMF (DO-219AB) PACKAGE

IN A NUTSHELL

High surge capability of 400 W at 10/1000 µs





Low profile (1 mm) SMF (D0-219AB) package

HALOGEN FREE ROHS

AEC-Q101 Oualified

COMPETITIVE ADVANTAGE

 Low avalanche breakdown voltage tolerance allows tighter design of electronic circuit



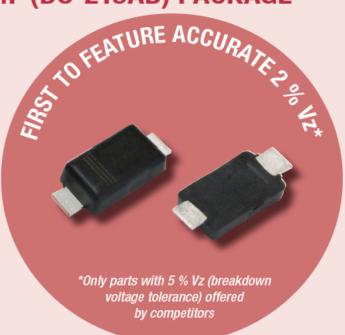
 Lower avalanche breakdown voltage tolerance = lower clamping voltage tolerance

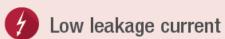






 Important when a transient voltage signal must be clamped close to the max voltage range!





Low noise technology





Very fast response time

Precise protection for key components



VTVS Series consists of 23 devices (VTVS5V0ASMF to VTVS63GSMF)

APPLICATIONS

Ideal for space-constrained electronics











PRIMARY CHARACTERISTICS					
V _{BR}	6.4 V to 78.2 V				
V _{wm}	5.0 V to 63 V				
P _{PPM}	400 W				
T _J max.	175 °C				
Polarity	Unidirectional				
Package	D0-219AB (SMF)				





VTVS Series: 400 W TVS in the SMF (DO-219AB) Package

VTVS Series TVS protection diodes are the industry's first to feature a 2 % breakdown voltage tolerance with 400 W surge capability at 10/1000 µs. The VTVS Series devices are ideal for line transient voltage protection in space-constrained portable electronics such as laptops, notebooks, tablets, smartphones, and external hard drives.

Advantages	Benefits
Low avalanche breakdown voltage tolerance	Tighter design of electronic circuits – TVS signal can be clamped close to maximum voltage range
Working voltages from 5 V to 63 V with breakdown voltage tolerances (Vz) of 2 % or 5 %	Competitors only offer parts with 5 % Vz
Low leakage current, low noise technology, and very fast response time	Precise protection for key components

<u>Datasheet</u>
Product sheet
Press release
Technical note





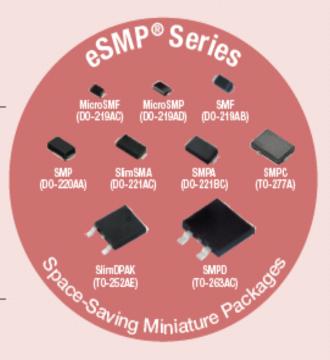
eSMP® SERIES

D LOW PROFILE PACKAGE SOLUTIONS FOR SELECT DIODES AND RECTIFIERS

eSMP® Packages enhanced Surface-Mount Power packages



Enable higher current and power efficiency with a unique design that promotes better thermal performance and reliability



Product technologies available in eSMP® series packages:

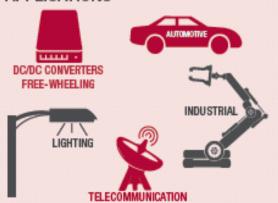
- ESD protection diodes
- PAR® TVS diodes
- TRANSZORR® TVS diodes.
- Zener diodes
- Avalanche rectifiers
- FRED Pt[®] rectifiers
- Schottky rectifiers
- · Standard and fast recovery rectifiers

Available in asymmetrical and

symmetrical flat type packages

- TMBS[®] rectifiers
- Ultrafast recovery rectifiers

APPLICATIONS



USEFUL LINKS 🚽 eSMP® series product overview: www.vishay.com/doc?49383

Diodes / rectifiers in eSMP® series package: www.vishav.com/landingpage/tradeshows/diodes/





eSMP® Series

eSMP® (enhanced Surface-Mount Power) Series packages are small, low-profile package solutions for select diodes and rectifiers product technologies.

Advantages	Benefits
Higher current and power efficiency	Better thermal performance and reliability
Available in asymmetrical and symmetrical flat type packages	Space-saving miniature packages allow for slimmer end products

Product Portfolio	
Product Evolution	
<u>Landing Page</u>	





STANDARD RECOVERY RECTIFIERS

ESD CAPABILITY

IN A NUTSHELL

- · Oxide planar chip technology
- ESD capability
 - Provide class H3B (> 8 kV) performance based on the AEC-Q101-001 human body model (contact mode) and / or JESD22-A114, class 3B



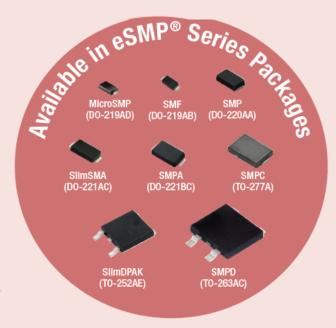
Electrical Static Discharge (ESD)



Current range from 0.7 A to 20 A



Reverse voltage from 100 V to 600 V



APPLICATIONS





- · General purpose
- Polarity protection
- · Rail to rail protection



Maximum operating junction temperature of +175 °C





Low forward voltage drop, low leakage current

AEC-Q101 Qualified Products have undergone part average testing (PAT) and statistical yield limit (SYL) analysis to ensure their electrical parameters meet the highest quality level for automotive applications



AEC-Q101 Qualified

Device ⁽¹⁾	eSMP [®] Package	I _{F(AV)}	V _{BR} Range	Max V	_F at I _F	AEC-Q101	Automotive
		(A)	(V)	(V)	(A)		Grade
SE07PB thru SE07PJ	SMP (D0-220AA)	0.7	100 to 600	1.05	0.7	No	No
MSE07PB thru MSE07PJ	MicroSMP (DO-219AD)	0.7	100 to 600	1.08	0.7	Yes	Yes
SE10PB thru SE10PJ	SMP (D0-220AA)	1.0	100 to 600	1.05	1.0	Yes	Yes
MSE1PB thru MSE1PJ	MicroSMP (DO-219AD)	1.0	100 to 600	1.10	1.0	Yes	Yes
MSX1PB thru MSX1PJ	MicroSMP (DO-219AD)	1.0	100 to 600	1.10	1.0	Yes	Yes
SE10FD thru SE10FJ	SMF (D0-219AB)	1.0	200 to 600	1.05	1.0	Yes	Yes
SE15PB thru SE15PJ	SMP (D0-220AA)	1.5	100 to 600	1.05	1.5	Yes	Yes
SE15FD thru SE15FJ	SMF (D0-219AB)	1.5	200 to 600	1.05	1.0	Yes	Yes
SE20PB thru SE20PJ	SMP (D0-220AA)	2.0	100 to 600	1.05	2.0	Yes	Yes
SE20FD thru SE20FJ	SMF (D0-219AB)	2.0	200 to 600	1.10	2.0	Yes	Yes
SE20AFB thru SE20AFJ	SlimSMA (DO-221AC)	2.0	100 to 600	1.10	2.0	Yes	No

Device ⁽¹⁾	eSMP [®] Package	I _{F(AV)}	V _{BR} Range	Max \	_F at I _F	AEC-Q101	Automotive
		(A)	(V)	(V)	(A)		Grade
SE20PAB thru SE20PAJ	SMPA (DO-221BC)	2.0	100 to 600	1.10	2.0	Yes	No
SE30AFB thru SE30AFJ	SlimSMA (DO-221AC)	3.0	100 to 600	1.10	3.0	Yes	No
SE30PAB thru SE30PAJ	SMPA (DO-221BC)	3.0	100 to 600	1.16	3.0	Yes	No
SE40PB thru SE40PJ	SMPC (T0-277A)	4.0	100 to 600	1.05	4.0	Yes	Yes
SE50PAB thru SE50PAJ	SMPA (DO-221BC)	5.0	100 to 600	1.16	5.0	Yes	No
SE70PB thru SE70PJ	SMPC (T0-277A)	7.0	100 to 600	1.05	7.0	Yes	Yes
SE80PWB thru SE80PWJ	SlimDPAK (T0252AE)	8.0	100 to 600	1.12	8	Yes	No
SE10DB thru SE10DJ	SMPD (TO-263AC)	10	100 to 600	1.15	10	Yes	No
SE100PWB thru SE100PWJ	SlimDPAK (T0252AE)	10	100 to 600	1.14	10	Yes	No
SE12DB thru SE12DJ	SMPD (TO-263AC)	12	100 to 600	1.15	12	Yes	No
SE20DB thru SE20DJ	SMPD (TO-263AC)	20	100 to 600	1.20	20	Yes	No

(1) Reverse voltage, where: A = 50 V, B = 100 V, C = 150 V, D = 200 V, F = 300 V, G = 400 V, H = 500 V, J = 600 V





Standard Recovery Rectifiers with ESD Capability

ESD capability combined with a wide range of current ratings provide class H3B (> 8 kV) performance based on the AEC-Q101-001 human body model (contact mode) and/or JESD22-A114, class 3B.

Advantages	Benefits
Standard recovery rectifiers with ESD capability available in a wide range of current ratings and reverse voltage ratings	Available in eSMP® packages that allow for slimmer end products

Product Sheet
Landing Page





TMBS® Rectifiers in eSMP® SERIES IN A

ENCH MOS BARRIER SCHOTTKY TECHNOLOGY IN SPACE-SAVING FOOTPRINTS | NUTSHELL AND LOW PROFILE PACKAGE SOLUTIONS





Reverse voltage from 45 V to 200 V

Current range from 1 A to 60 A





Low profile package heights

Low power losses and high efficiency







Trench MOS Schottky technology provides low forward voltage drop

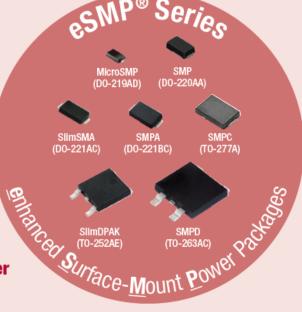


Enable higher current and **power** efficiency with a unique design that promotes better thermal performance and reliability

MAXIMUM OPERATING JUNCTION TEMPERATURE

Up to 175 °C

For M type Schottky barrier part numbers



шш DC/DC CONVERTERS FREE-WHEELING



APPLICATIONS



Select TMBS® rectifiers available in the following packages:

- MicroSMP (D0-219AD)
- SlimDPAK (TO-252AE)
- SlimSMA (D0-221AC)
- SMP (DO-220AA)
- SMPA (D0-221BC)
- SMPC (TO-277A)
- SMPD (T0-263AC)

AEC-Q101 Qualified



TMBS® AEC-Q101 Qualified Products have undergone part average testing (PAT) and statistical yield limit (SYL) analysis to ensure their electrical parameters meet the highest

quality level for automotive



PAT

Qualified

eSMP® Series Packages Overview

applications



For Technical Questions: DiodesAmericas@vishay.com, DiodesEurope@vishay.com, or DiodesAsia@vishay.com





TMBS® Rectifiers in eSMP® Series

Trench MOS Barrier Schottky (TMBS) technology in space-saving footprints and low-profile packages.

Advantages	Benefits
Trench MOS Schottky technology provides low forward voltage drops	Low power losses and high efficiency

Product Overview
<u>Landing Page</u>
Video: TMBS Rectifiers





FRED Pt® RECTIFIERS IN eSMP® SERIES

SPACE-SAVING FOOTPRINTS AND LOW PROFILE PACKAGE SOLUTIONS FOR ALL

MAJOR APPLICATIONS

FRED Pt® (Fast Recovery Epitaxial Diodes) products are based on a Pt doping technology that allows maximum operating

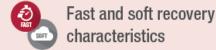
junction temperature Up to 175 °C



Current range from 1 A to 30 A

Reverse voltage: 100 V, 200 V, and 600 V





Low leakage currents



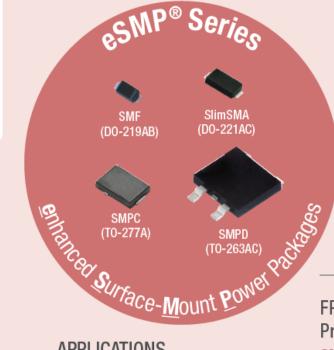


Reduce switching losses



eSMP® Series Packages Overview





APPLICATIONS









FRED Pt® rectifiers available in the following packages:

- Standard Products SMF (DO-219AB) SlimSMA (D0-221AC) SMPC (T0-277A) SMPD (TO-263AC)
- AEC-Q101 Qualified Products SMF (DO-219AB) SlimSMA (D0-221AC) SMPC (T0-277A) SMPD (TO-213AC)

FRED Pt® AEC-Q101 Qualified Products have undergone part average testing (PAT) and statistical yield limit (SYL) analysis to ensure their electrical parameters meet the **highest quality** level for automotive applications





AEC-Q101 Qualified





FRED Pt® Rectifiers in eSMP® Series Packages

Space-saving footprints and low-profile package solutions for all major applications.

Advantages	Benefits
FRED Pt® (Fast Recovery Epitaxial Diodes) products are based on a PT doping technology that allows maximum operating temperature up to 175 °C	Allow for more robust designs
Low leakage current ratings and low forward voltage drops	Reduce switching losses, provide fast and soft recovery characteristics

Product Overview	
<u>Landing Page</u>	





PLZ SERIES

ZENER DIODES IN MicroSMF (DO-219AC) PACKAGE

NUTSHELL

500 mW power dissipation



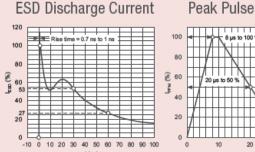
Ultra compact MicroSMF (DO-219AC) flat lead package; < 0.6 mm low profile

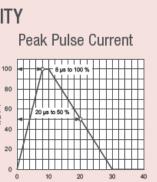
Extremely tight tolerances of ± 2.5 %

COMPETITIVE ADVANTAGE

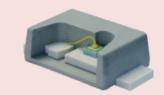
Combining extremely tight tolerances with low leakage current and excellent stability, the PLZ Series is designed to withstand **ESD pulses** of 8000 V (human body model)

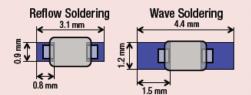
ESD / SURGE CAPABILITY





1.9 mm 1.3 mm 0.6 mm MicroSMF (DO-219AC





Saves PCB space



Increases pick and place speeds on assembly lines

AEC-Q101 Qualified

APPLICATIONS

Voltage stabilization and reference voltage generation in power supplies and LED lighting



LIGHTING









Primary Characteristics	
V _z range nom.	2.0 V to 39 V
Test current I _{ZT}	5 mA to 20 mA
V _z specification	Pulse current
Int. construction	Single





ESD PROTECTION DIODES

IN ULTRA COMPACT CHIP LEVEL PACKAGE (CLP)



Single-line and 4-line **ESD protection** diodes



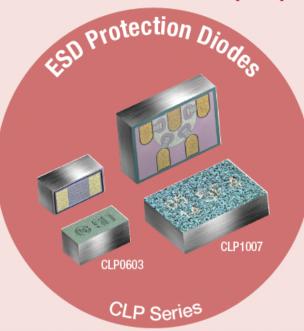
Working range: ± 3.3 V to ± 10 V



Low leakage current: < 0.1 µA



AEC-Q101 versions available



IN A NUTSHELL

Operating temperature range: -55 °C to +150 °C



APPLICATIONS

ESD protection of high speed interfaces in:









AUTOMOTIVE ENTERTAINMENT SYSTEMS

Vishay P/N		, (V)	l _n	C _p	Contact Discharge	Air Discharge	AEC-Q101
	Unidirectional	Bidirectional	(μÄ)	(PĚ)	(KV)	(KV)	Available
VBUS03B1-SD0		± 3.3	< 0.05	0.29 typ.	± 16	± 16	Yes
VBUS05B1-SD0		± 5.5	< 0.05	0.29 typ.	± 16	± 16	Yes
VBUS54FD-SD1	± 5.5		< 0.1	0.9 typ.	± 15	± 15	No
VCUT03E1-SD0		± 3.3	< 0.1	< 14	± 30	± 30	Yes
VCUT05E1-SD0		± 5.5	< 0.1	< 14	± 30	± 30	Yes
VCUT10A1-SD0		± 10	< 0.1	< 9	± 24	± 24	Yes





TRANSZORB® TVS IN SMB (DO-214AA)

OFFER TIGHTER ± 3.5 % BREAKDOWN VOLTAGE TOLERANCE

SMB

- **5.4** mm —

FEATURES



Tightened breakdown voltage tolerance of $\pm 3.5 \%$

High peak pulse surge currents from 2.03 A to 65.9 A





Excellent clamping capability from 9.1 V to 301 V

High surge capability to 600 W at 10/1000 µs







2.3 mm

APPLICATIONS



Designed to **protect** sensitive electronics against voltage transients induced by inductive load switching and lightning

General voltage surge protection in consumer, computer, industrial, and telecommunications equipment









To view datasheet, click here

INDUSTRIAL

Device	Breakde V a	Breakdown Voltage V _{ss} at L _r ⁽¹⁾ (V)		Stand-Off Voltage	Leakage at	Max Peak Pulse Surge Curzent	Max Clamping Voltage at I _{rre}
Туре	min	max	Լ (A)	V _{wm} (V)	V _{wm} I _D (μΑ) ⁽²⁾	I _{PPM} (A) ⁽³⁾	V _c (V)
SMBJ5.0D*	6.50	6.97	10	5.0	500	65.9	9.1
SMBJ6.0D*	6.77	7.27	10	6.0	500	58.9	10.2
SMBJ6.5D*	7.33	7.87	10	6.5	300	54.5	11.0
SMBJ7.0D*	7.90	8.48	10	7.0	150	50.8	11.8
SMBJ7.5D*	8.46	9.08	1.0	7.5	75	47.2	12.7
SMBJ8.0D*	9.03	9.69	1.0	8.0	35	44.8	13.4
SMBJ8.5D*	9.57	10.3	1.0	8.5	15	42.2	14.3
SMBJ9.0D*	10.2	10.9	1.0	9.0	5.0	39.7	15.1
SMBJ10D*	11.3	12.1	1.0	10	2.0	35.9	16.7
SMBJ11D*	12.4	13.3	1.0	11	2.0	33.5	17.9
SMBJ12D*	13.5	14.5	1.0	12	2.0	30.6	19.6
SMBJ13D*	14.6	15.7	1.0	13	0.5	28.3	21.2
SMBJ14D*	15.8	17.0	1.0	14	0.5	26.2	22.9
SMBJ15D*	17.0	18.2	1.0	15	0.5	25.0	24.0
SMBJ16D*	18.1	19.4	1.0	16	0.5	23.4	25.6
SMBJ17D*	19.2	20.6	1.0	17	0.5	22.1	27.2
SMBJ18D*	20.3	21.8	1.0	18	0.5	20.8	28.8
SMBJ20D*	22.5	24.2	1.0	20	0.5	18.8	32.0
SMBJ22D*	24.8	26.6	1.0	22	0.5	17.1	35.1
SMBJ24D*	27.1	29.1	1.0	24	0.5	15.6	38.4
SMBJ26D*	29.3	31.5	1.0	26	0.5	14.5	41.6
SMBJ28D*	31.6	33.9	1.0	28	0.5	13.4	44.7
SMBJ30D*	33.8	36.3	1.0	30	0.5	12.6	47.7
SMBJ33D*	37.3	40.0	1.0	33	0.5	11.5	52.5
SMBJ36D*	40.6	43.6	1.0	36	0.5	10.5	57.3
SMBJ40D*	45.1	48.4	1.0	40	0.5	9.43	63.6
SMBJ43D*	48.5	52.1	1.0	43	0.5	8.76	68.5
SMBJ45D*	50.8	54.5	1.0	45	0.5	8.40	71.6
SMBJ48D*	54.1	58.1	1.0	48	0.5	7.90	76.3
SMBJ51D*	57.6	61.8	1.0	51	0.5	7.40	81.2
SMBJ54D*	60.9	65.4	1.0	54	0.5	7.00	85.9
SMBJ58D*	65.4	70.2	1.0	58	0.5	6.50	92.3
SMBJ60D*	67.7	72.7	1.0	60	0.5	6.28	95.5
SMBJ64D*	72.2	77.5	1.0	64	0.5	5.88	102
SMBJ70D*	79.0	84.8	1.0	70	0.5	5.40	111
SMBJ75D*	84.6	90.8	1.0	75	0.5	5.06	119
SMBJ78D*	88.1	94.4	1.0	78	0.5	4.86	124
SMBJ85D*	95.7	103	1.0	85	0.5	4.46	135
SMBJ90D*	102	109	1.0	90	0.5	4.17	144
SMBJ100D*	113	121	1.0	100	0.5	3.77	159
SMBJ110D*	124	133	1.0	110	0.5	3.45	174
SMBJ120D*	135	145	1.0	120	0.5	3.15	190
SMBJ130D*	146	157	1.0	130	0.5	2.94	206
SMBJ150D*	170	182	1.0	150	0.5	2.53	239
SMBJ160D*	181	194	1.0	160	0.5	2.34	256
SMR 1170D*		206	1.0	170	0.5	2 23	270



2.03

301



TRANSIENT VOLTAGE SUPPRESSORS IN eSMP® SERIES PACKAGES

SNAPSHOT



High temperature stability in high

reliability conditions to +185 °C

0

Low profile eSMP® packages:

MicroSMP (D0-219AD): 0.65 mm typical

SlimSMA (DO-221AC): 0.95 mm

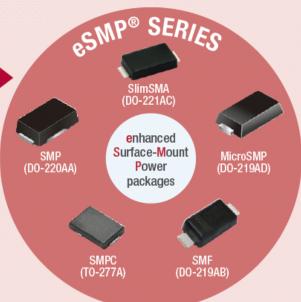
SMF (D0-219AB): 1.0 mm SMP (D0-220AA): 1.0 mm

SMPC (T0-277A): 1.1 mm typical

AEC-Q101 qualified and

AUTOMOTIVE GRADE

Automotive Grade versions available



Applications

Protect sensitive electronics against voltage transients







COMPUTER





TRANSZORB® TVS diodes are recommended for general applications



PAR® TVS diodes are the first choice for automotive applications

Series	Package Outline	Power Rating (W)	TVS Polarity	V _{BR} Min. (V)	V _{WM} Min. (V)	V _{WM} Max. (V)	T _J Max. (°C)	Product Line
MSMP6.0A thru MSMP20A	MicroSMP (D0-219AD)	150	Unidirectional	6.67	6	20	150	TransZorb® TVS
MSP3V3, MSP5.0A	MicroSMP (D0-219AD)	150	Unidirectional	4.1	3.3	5	150	TransZorb® TVS
SMP3V3 thru SMP36A	SMP (D0-220AA)	400	Unidirectional	4.1	3.3	36	150	TransZorb® TVS
TPSMP6.8A thru TPSMP43A	SMP (D0-220AA)	400	Unidirectional	6.45	5.8	36.8	185	PAR® TVS
SMPC5.0A thru SMPC36A, SMPC22AN thru SMPC85AN	SMPC (T0-277A)	1500	Unidirectional	6.4	5	85	150	TransZorb® TVS
TPC11CA thru TPC36CA	SMPC (T0-277A)	1500	Bidirectional	10.5	9.4	30.8	185	PAR® TVS
TPC6.8A thru TPC51A	SMPC (T0-277A)	1500	Unidirectional	6.45	5.8	43.6	185	PAR® TVS
VTVS3V3ASMF to VTVS63GSMF	SMF (D0-219AB)	400	Unidirectional	6.4	3.3	63	175	TransZorb® TVS
SMA6F5.0A thru SMA6F20A	SlimSMA (DO-221AC)	600	Unidirectional	6.4	5	20	175	TransZorb® TVS
TA6F6.8A thru TA6F51A	SlimSMA (D0-221AC)	600	Unidirectional	6.45	5.8	43.6	185	PAR® TVS





SiC46X microBUCK® SERIES

NUTSHELL

4.5 V TO 60 V BUCK REGULATORS

75 W
UP
TO
OUTPUT POWER

4.5 V to 60 V buck regulator capable of delivering up to 75 W output power

COMPETITIVE ADVANTAGE

Highly Integrated

Competition

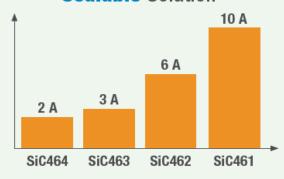
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SiC462 Efficiency at 300 kHz



2 A, 3 A, 6 A, and 10 A buck regulators in compact MLP 5x5 package

Scalable Solution



For Technical Questions: powerictechsupport@vishay.com

Rugged and **Reliable**



APPLICATIONS

Design your application using our **online PowerCAD Simulation Tool**









BATTERY OPERATED VEHICLE / EQUIPMENT









SiC46x microBUCK® Series

Achieve Over 72 W output power with the SiC46x buck regulator! With a 4.5 V to 60 V input voltage range, the SiC462 synchronous buck regulator enables simple, flexible, and rugged designs. The family of 2 A, 3 A, 6 A, and 10 A parts in a single package footprint enables designs that can be scaled as the user's power needs change.

Advantages	Benefits
The SiC46x microBUCK family integrates a rugged controller design and benchmark MOSFETs in a compact 5 x 5 MLP package	Compact, low part count design enabling high power density
Efficiencies of Up to 98%	Excellent thermal performance and long term reliability
Low Quiescent current	Excellent light load efficiency

microBUCK® Product Portfolio

PowerCAD Simulator Tool

AppNote: Creating a Negative Output Voltage Using a Buck Converter





POWER MOSFETS

NUTSHELL

Low Voltage TrenchFET®





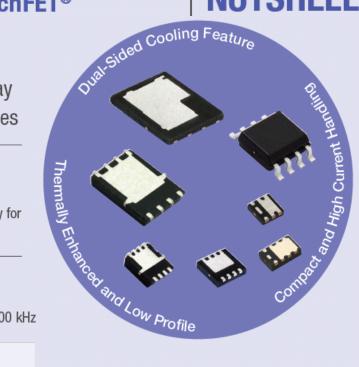
 $\mathbf{R}_{\mathbf{DS(on)}}$ n-channel **MOSFETs** in an array of advanced packages

- Less than 0.58 mΩ
- Breakdown voltages: 25 V to 30 V
- Excellent R_{ns} Q_a FOM improves efficiency for switch-mode power supplies

TYPICAL EFFICIENCY IMPROVEMENT **EXPECTATION**

Benchmarking condition 12.9 V_{IN}, 1.8 V_{OUT}, 800 kHz





Dual-sided cooling feature





Higher efficiency



Increased power density

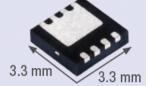
Space-saving packages

SiA468DJ

SiSS02DN



Up to 37.8 A continuous I



 $< 1.2 \text{ m}\Omega$ 10.89 mm² footprint

APPLICATIONS















Power MOSFET Low Voltage TrenchFET®

Vishay Siliconix leads the industry in the development of power semiconductor products that improve the efficiency of power management circuitry in end products while reducing space requirements.

Advantages	Benefits			
Industry's Lowest R _{DS(ON)}	Increases efficiency, minimizes power loss and achieves higher power delivery per device. Reduces the number of component required.			
Increased Power Density	Highly efficient devices in an array of compact packages enable PCB optimization and reduce footprint requirement.			
Advanced Package Options	Dual sided cooling option supports optimization of thermal management designs. The footprint is compatible to standard PowerPAK SO-8 and provides drop-in replacement.			

SPICE Models
Parametric Search
Application Note MOSFETs



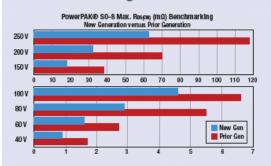


POWER MOSFET

MEDIUM VOLTAGE TRENCHFET®

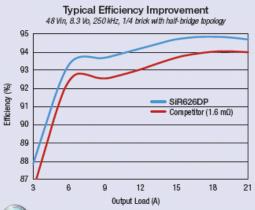
IN A NUTSHELL

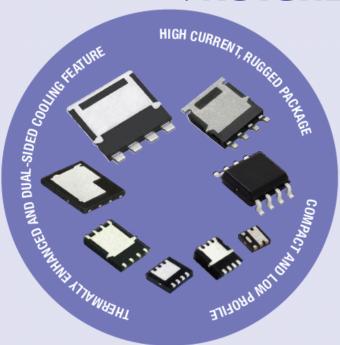
Breakdown voltages: 40 V to 250 V



Industry's lowest R_{DS}-Q_{oss} Figure-of-merit (FOM) in an advanced package array

Excellent dynamic parameters optimize switching characteristics





Double-cooled PowerPAK S0-8



THIN PROFILE with 0.56 mm typical height Footprint COMPATIBLE to PowerPAK SO-8 $R_{\text{DS/ON}}$ as low as 0.73 m Ω

Enable the **HIGHEST** efficiency



INCREASE power density

REDUCE component count



COMPACT and **HIGHLY EFFICIENT** devices enable layout optimization



80 % footprint reduction from D2PAK

75 % lower package profile

APPLICATIONS









RENEWABLE ENERGY





Power MOSFET Medium Voltage TrenchFET®

Vishay Siliconix leads the industry in the development of power semiconductor products that improve the efficiency of power management circuitry in end products while reducing space requirements.

Advantages	Benefits			
Industry's Lowest R _{DS} - Q _{OSS} Figure of Merit	Enables the highest efficiency by reducing the power loss from conduction and switching simultaneously, especially for ZVS topologies. The improvement also helps increasing power density and reducing component count.			
Excellent Dynamic Parameters - Low Q_g , Q_{gd} and Q_{OSS}	Reduces undesired power loss from switching and optimizes switching characteristics. The more efficient converter also operates at lower temperature.			
Array of Advanced Package Options	New double-cooled package enables optimization of thermal management design. The high performance devices in compact packages supports layout optimization.			

SPICE Models
Parametric Search
Application Note: MOSFETs





Power MOSFETs | IN A

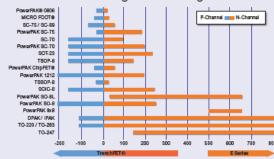
TrenchFET® AND E SERIES

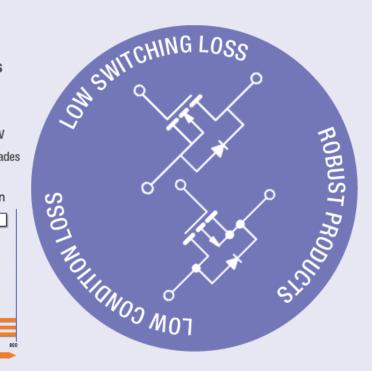
IN A NUTSHELL

Broad range of power MOSFETS in a wide selection of advanced packages

- N- and p-channel families
- Breakdown voltages: -200 V to 800 V
- Wide range of gate drive voltages starting at 1.2 V
- Commercial, automotive, and medical product grades

Breakdown Voltage and Package Selection



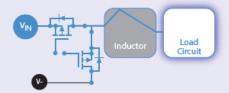


Application-Specific Technology Platforms

Optimized with lowest Rds(on) for load switch applications



Optimized for lowest gate charge and capacitances for fast switching



MARKETS AND APPLICATIONS





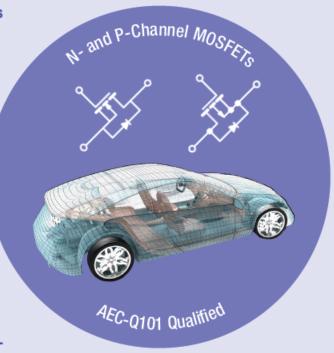




AUTOMOTIVE TrenchFET®

SQ SERIES POWER MOSFETs

- Wide range of N- and P-channel MOSFETs
 - N-ch $V_{ps} = 12 \text{ V to } 300 \text{ V}$
 - $P-ch V_{ps} = -12 V to -200 V$
- Available in single, dual, and dual asymmetric configurations
- Highly efficient packages with power density up to 11 W/mm²
 - $R_{DS(ON)}$ down to 1 m Ω
- AEC Q-101 Qualified to + 175 °C
- Latest trench technologies optimized for low conduction and low switching losses
- Product testing includes extended temp screening with dynamic PAT, SYL, and SBL to reduce defects



IN A NUTSHELL APPLICATIONS









INFOTAINMENT



BRAKING

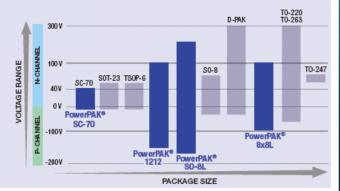




ELECTRIC VEHICLES

POWER TRAIN

SQ Package Portfolio



$\textbf{Compact PowerPAK} \textbf{@ packages} \sim \textbf{Optimized for high board-level reliability}$







PowerPAK® S0-8L 5 mm x 6 mm



· ·

PowerPAK® 1212 3.3 mm x 3.3 mm



PowerPAK® SC-70 2 mm x 2mm



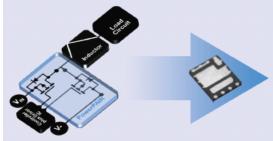
KGD Known Good Die 1 m x 1 mm to 8 mm x 12 mm



POWERPAIR® MOSFETS IN A

INTEGRATED DUAL-MOSFET POWER STAGE

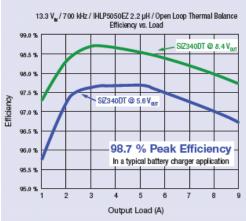
Input Voltage Range: 4.5 V to 24 V **Internally Connected Half-Bridge**

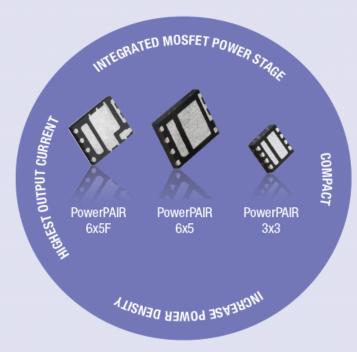


Supports Single or Multi-Phase Designs, Reduces PCB Footprint Area for MOSFET Components

Optimized Gen IV MOSFET Pair

Enables High Efficiency





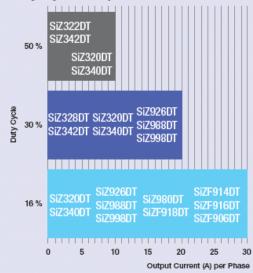
PowerPAIR 6x5F for Layout Optimization

Simplifies Placement of Input Capacitor Separation of "Power" and "Signal" Partition



NUTSHELL

WIDE RANGE of Solutions That Support Popular Output Power and **Duty Cycle Requirements**



APPLICATIONS







COMPUTERS

GRAPHIC CARDS

CONSOLES



EQUIPMENT



DRONES



CONSUMER **ELECTRONICS**

INTERFACES





P-CHANNEL MOSFETS IN A

-12 V TO -40 V TrenchFET® GEN III AND IV

Breakdown voltages: -12 V to -40 V

Industry's lowest R_{DS(ON)}

in an array of advanced packages

Minimize power loss and voltage drop



Part #	Si8851EDB	Sis A01 DN	Si7155DP
V _{DS}	-20 V	-20 V -30 V	
R _{DS(ON)}	< 8 mΩ	< 4.9 mΩ	$< 3.6 \ \text{m}\Omega$
Footprint (mm)	2.4 x 2	3.3 x 3.3	6 x 5

Up to 31 A continuous drain current rating in 2 mm x 2 mm package

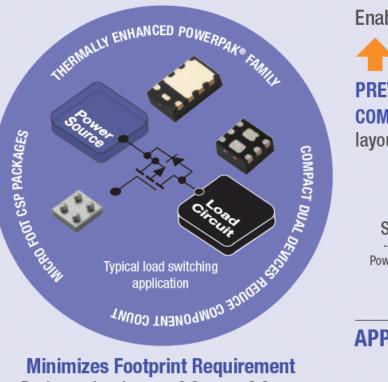
PowerPAK® SC-70 2.05 mm x 2.05 mm x 0.75 mm



Part#	SiA467EDJ	SiA437DJ		
V _{DS}	-12 V	-20 V		
R _{DS(ON)}	< 13 mΩ	< 14.5 mΩ		
Continuous I _D	31	29.7		

Battery application driven features

- Guaranteed 1.5 V rated R_{DS(ON)}
- ESD protection up to 8 kV (HBM)



Minimizes Footprint Requirement

Package size down to 0.8 mm x 0.6 mm





MICRO FOOT® 0.8 mm x 0.8 mm

PowerPAK® 0806 0.8 mm x 0.6 mm

NUTSHELL

Enable **LONGER** battery life



INCREASE efficiency of power delivery

PREVENT undesired fault signals **COMPACT** and space saving PCB **layout OPTIMIZATION**





SiSA01DN

-30 V. 4.9 mΩ PowerPAK® 1212-8 10.89 mm²

S0-8 equivalent

-30 V. 5 mΩ SO-8 31 mm²

65 % Smaller footprint

APPLICATIONS



BATTERY POWERED EQUIPMENT



NOTEBOOKS / **TABLETS**



GAME CONSOLES





